

# HD74LVCZ244A

# Octal Buffers / Line Drivers with 3-state Outputs

REJ03D0371-0300 (Previous ADE-205-230A (Z)) Rev.3.00 Aug. 18, 2004

#### **Description**

The HD74LVCZ244A has eight line drivers with three state outputs in a 20 pin package. This device is a noninverting buffer and has two active low enables ( $1\overline{G}$  and  $2\overline{G}$ ). Each enable independently controls four buffers.

When  $V_{CC}$  is between 0 and 1.5 V, the device is in the high impedance state during power up or power down.

Low voltage and high-speed operation is suitable at battery drive product (note type personal computer) and low power consumption extends the life of a battery for long time operation.

#### **Features**

- $V_{CC} = 2.7 \text{ to } 5.5 \text{ V}$
- All inputs  $V_{IH}$  (Max) = 5.5 V (@ $V_{CC}$  = 0 to 5.5 V)
- All outputs  $V_0$  (Max) = 5.5 V (@ $V_{CC}$  = 0 V or output off state)
- Typical  $V_{OL}$  ground bounce < 0.8 V (@ $V_{CC}$  = 3.3 V, Ta = 25°C)
- Typical  $V_{OH}$  undershoot > 2.0 V (@ $V_{CC}$  = 3.3 V, Ta = 25°C)
- High impedance state during power up and power down
- Power off disables outputs, permitting live insertion
- High output current  $\pm 24$  mA (@V<sub>CC</sub> = 3.0 to 5.5 V)
- Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
HD74LVCZ244AFPEL	SOP-20 pin (JEITA)	FP-20DAV	FP	EL (2,000 pcs/reel)
HD74LVCZ244ATELL	TSSOP-20 pin	TTP-20DAV	Т	ELL (2,000 pcs/reel)

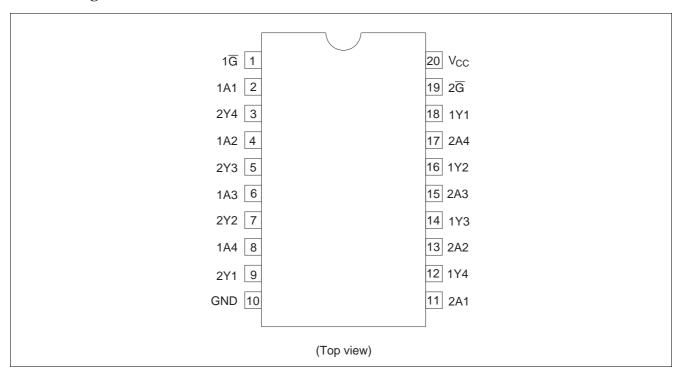
#### **Function Table**

#### Inputs

G	A	Output Y
Н	X	Z
L	Н	Н
L	L	L

- H: High level
- L: Low level
- X: Immaterial
- Z: High impedance

### **Pin Arrangement**



# **Absolute Maximum Ratings**

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V <sub>CC</sub>	-0.5 to 7.0	V	
Input voltage	Vı	-0.5 to 7.0	V	
Output voltage	Vo	-0.5 to 7.0	V	Output "Z" or V <sub>CC</sub> : OFF
		-0.5 to V <sub>CC</sub> +0.5		Output "H" or "L"
Input diode current	I <sub>IK</sub>	-50	mA	V <sub>1</sub> < 0
Output diode current	I <sub>OK</sub>	-50	mA	V <sub>O</sub> < 0
Output current	Io	±50	mA	
V <sub>CC</sub> , GND current	I <sub>CC</sub> or I <sub>GND</sub>	±100	mA	
Storage temperature	Tstg	-65 to 150	°C	

Note: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

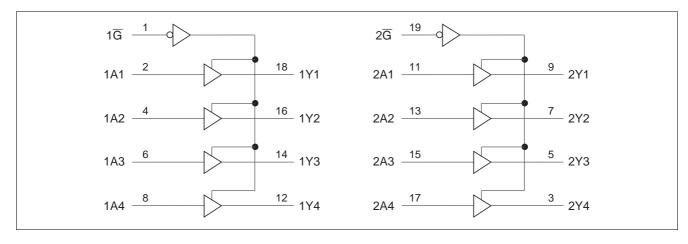
#### HD74LVCZ244A

# **Recommended Operating Conditions**

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	$V_{CC}$	2.7 to 5.5	V	At operation
Input voltage	VI	0 to 5.5	V	
Output voltage	Vo	0 to 5.5	V	Output "Z" or V <sub>CC</sub> : OFF
		0 to V <sub>CC</sub>		Output "H" or "L"
Output current	I <sub>OH</sub>	-12	mA	V <sub>CC</sub> = 2.7 V
		-24 <sup>*1</sup>		$V_{CC} = 3.0 \text{ to } 5.5 \text{ V}$
	I <sub>OL</sub>	12	mA	V <sub>CC</sub> = 2.7 V
		24 *1		$V_{CC} = 3.0 \text{ to } 5.5 \text{ V}$
Input rise / fall time	t <sub>r</sub> , t <sub>f</sub>	0 to 6	ns / V	
Operating temperature	Та	-40 to +85	°C	

Note: 1. Duty cycle ≤ 50%

### Logic Diagram



### **Electrical Characteristics**

 $(Ta = -40 \text{ to } 85^{\circ}C)$ 

Item	Symbol	V <sub>CC</sub> (V)	Min	Тур	Max	Unit	Test Conditions
Input voltage	V <sub>IH</sub>	2.7 to 3.6	2.0	_	_	V	
		4.5 to 5.5	V <sub>CC</sub> ×0.7	_	_	_	
	V <sub>IL</sub>	2.7 to 3.6	_	_	0.8	V	
		4.5 to 5.5	_	_	V <sub>CC</sub> ×0.3	_	
Output voltage	V <sub>OH</sub>	2.7 to 5.5	V <sub>CC</sub> -0.2	_	_	V	$I_{OH} = -100 \mu A$
		2.7	2.2	_	_	_	I <sub>OH</sub> = -12 mA
		3.0	2.4	_	_	_	
		3.0	2.2	_	_	_	I <sub>OH</sub> = -24 mA
		4.5	3.8	_	_	_	
	V <sub>OL</sub>	2.7 to 5.5	_	_	0.2	V	I <sub>OL</sub> = 100 μA
		2.7	_	_	0.4	_	I <sub>OL</sub> = 12 mA
		3.0	_	_	0.55	_	I <sub>OL</sub> = 24 mA
		4.5	_	_	0.55	_	
Input current	I <sub>IN</sub>	0 to 5.5	_	_	±5	μΑ	V <sub>IN</sub> = 0 to 5.5 V
Off state output	l <sub>OZ</sub>	2.7 to 5.5	_	_	±5	μΑ	V <sub>OUT</sub> = 0 to 5.5 V
current	l <sub>OZPU</sub>	0 to 1.5	_	_	±5		$V_{OUT} = 0.5 \text{ to } 5.5 \text{ V},$
	I <sub>OZPD</sub>	1.5 to 0	_	_	±5		Output enable = don't care
Output leak current	l <sub>OFF</sub>	0	_	_	±5	μΑ	$V_{IN}$ or $V_O = 5.5 \text{ V}$
Quiescent supply	Icc	2.7 to 3.6	_	_	225	μΑ	$V_{IN} = 3.6 \text{ to } 5.5 \text{ V}^{*1}, I_{O} = 0$
current		2.7 to 5.5	_	_	350		$V_{IN} = V_{CC}$ or GND
	$\Delta I_{CC}$	2.7 to 3.6	_	_	500	μΑ	$V_{IN}$ = one input at ( $V_{CC}$ -0.6) $V$ ,
							other inputs at V <sub>CC</sub> or GND
Input capacitance	C <sub>IN</sub>	3.3	_	3.4	_	pF	$V_{IN} = V_{CC}$ or GND
Output capacitance	Co	3.3	_	7.5	_	pF	$V_{OUT} = V_{CC}$ or GND

Note: 1. This applies in the disabled state only.

# **Switching Characteristics**

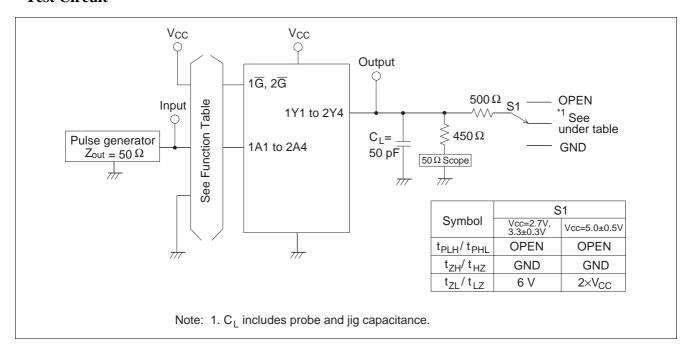
 $(Ta = -40 \text{ to } 85^{\circ}C)$ 

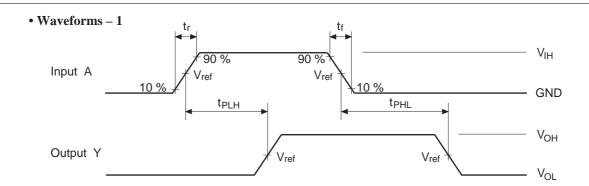
Item	Symbol	V <sub>CC</sub> (V)	Min	Тур	Max	Unit	FROM (Input)	TO (Output)
Propagation delay time	t <sub>PLH</sub>	2.7	_	_	6.9	ns	А	Υ
	$t_{PHL}$	3.3±0.3	1.5	_	5.9			
		5.0±0.5	_	_	4.5			
Output enable time	t <sub>ZH</sub>	2.7	_	_	8.6	ns	G	Υ
	$t_{ZL}$	3.3±0.3	1.5	_	7.6			
		5.0±0.5	_	_	6.1			
Output disable time	t <sub>HZ</sub>	2.7	_	_	6.8	ns	G	Υ
	$t_{LZ}$	3.3±0.3	1.5	_	6.5			
		5.0±0.5	_	_	5.5			
Between output pin skew *1	t <sub>OSLH</sub>	2.7	_	_	_	ns		
	toshl	3.3±0.3	_	_	1.0			
		5.0±0.5	_	_	1.0			

Note: 1. This parameter is characterized but not tested.

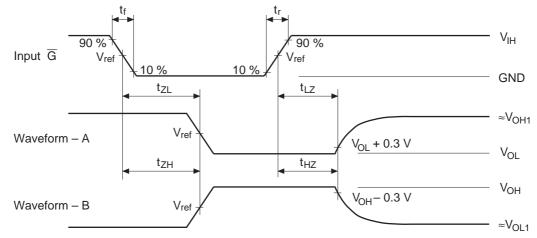
 $t_{\text{OSLH}} = |t_{\text{PLHm}} - t_{\text{PLHn}}|, \ t_{\text{OSHL}} = |t_{\text{PHLm}} - t_{\text{PHLn}}|$ 

### **Test Circuit**





#### • Waveforms - 2

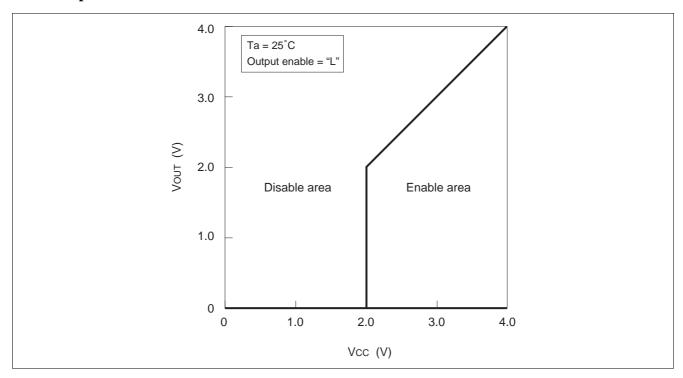


TEST	Vcc=2.7V, 3.3±0.3V	Vcc=5.0±0.5V
$V_{IH}$	2.7 V	V <sub>CC</sub>
$V_{ref}$	1.5 V	50%V <sub>CC</sub>
$V_{OH1}$	3 V	V <sub>CC</sub>
$V_{OL1}$	GND	GND

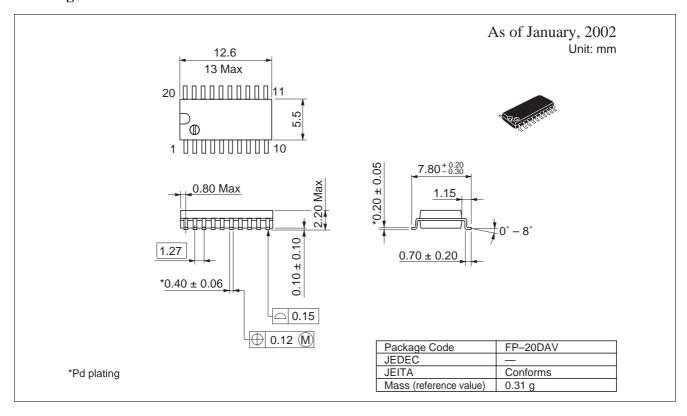
Notes: 1. Input waveform: PRR = 10 MHz, duty cycle 50%,  $t_r$  = 2.5 ns,  $t_f$  = 2.5 ns

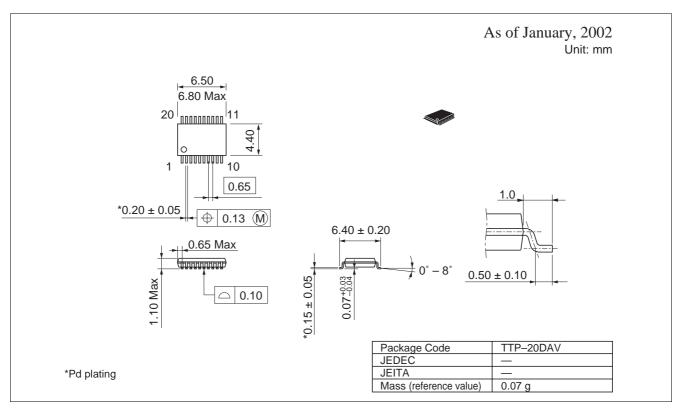
- 2. Waveform A shows input conditions such that the output is "L" level when enabled by the output control.
- 3. Waveform B shows input conditions such that the output is "H" level when enabled by the output control.

# Power up / down Characteristics



### **Package Dimensions**





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